2SD1445, 2SD1445A

Silicon NPN epitaxial planar type

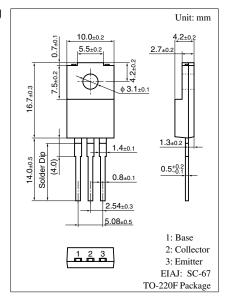
For power amplification, power switching and low-voltage switching Complementary to 2SB0948 (2SB948) and 2SB0948A (2SB948A)

■ Features

- ullet Low collector to emitter saturation voltage $V_{CE(sat)}$
- High-speed switching
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit
Collector to base	2SD1445	V_{CBO}	40	V
voltage	2SD1445A		50	
Collector to	2SD1445	V_{CEO}	20	V
emitter voltage	2SD1445A		40	
Emitter to base voltage		V_{EBO}	5	V
Peak collector current		I_{CP}	20	A
Collector current		I_C	10	A
Collector power	$T_C = 25^{\circ}C$	P_{C}	40	W
dissipation	$T_a = 25^{\circ}C$		2	
Junction temperature		T _j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C



■ Electrical Characteristics $T_C = 25$ °C

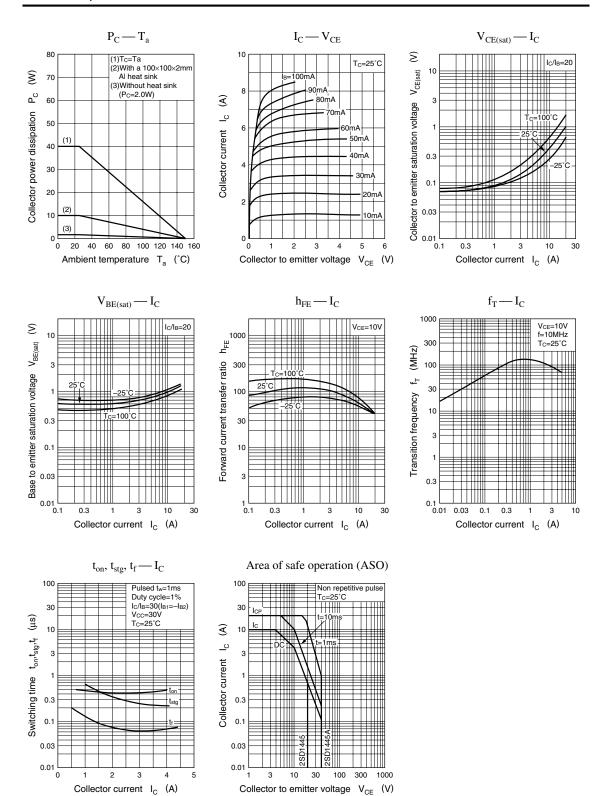
Parameter	•	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff	2SD1445	I_{CBO}	$V_{CB} = 40 \text{ V}, I_{E} = 0$			50	μΑ
current	2SD1445A		$V_{CB} = 50 \text{ V}, I_{E} = 0$			50	
Emitter cutoff current		I_{EBO}	$V_{EB} = 5 \text{ V}, I_{C} = 0$			50	μΑ
Collector to emitter	2SD1445	V _{CEO}	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	20			V
voltage	2SD1445A			40			
Forward current transfe	er ratio	h _{FE1}	$V_{CE} = 2 \text{ V}, I_{C} = 0.1 \text{ A}$	45			
		h _{FE2} *	$V_{CE} = 2 \text{ V}, I_{C} = 3 \text{ A}$	90		260	
Collector to emitter satu	ration voltage	V _{CE(sat)}	$I_C = 10 \text{ A}, I_B = 0.33 \text{ A}$			0.6	V
Base to emitter saturati	on voltage	V _{BE(sat)}	$I_C = 10 \text{ A}, I_B = 0.33 \text{ A}$			1.5	V
Transition frequency		f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}, f = 10 \text{ MHz}$		120		MHz
Collector output capac	itance	C_{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		200		pF
Turn-on time		t _{on}	$I_C = 3 A$, $I_{B1} = 0.1 A$, $I_{B2} = -0.1 A$,		0.3		μs
Storage time		t _{stg}	$V_{CC} = 20 \text{ V}$		0.4		μs
Fall time		t_{f}			0.1		μs

Note) *: Rank classification

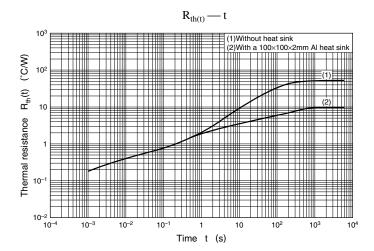
Rank	Q	P		
h_{FE2}	90 to 180	130 to 260		

Note) The part numbers in the parenthesis show conventional part number. Ordering can be made by the common rank (PQ rank h_{FE2} = 90 to 260) in the rank classification. (2SD1445A only)

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